



## 1, 2, 4 and 8-Channel Very Low Capacitance ESD Protectors

### Features

- 1,2,4 and 8 channels of ESD protection
- Very low loading capacitance (1.0pF typical)
- $\pm 6$  kV ESD protection per channel (IEC 61000-4-2 standard)
- Available in SOT23, SOT143, SC70 and MSOP packages

### Applications

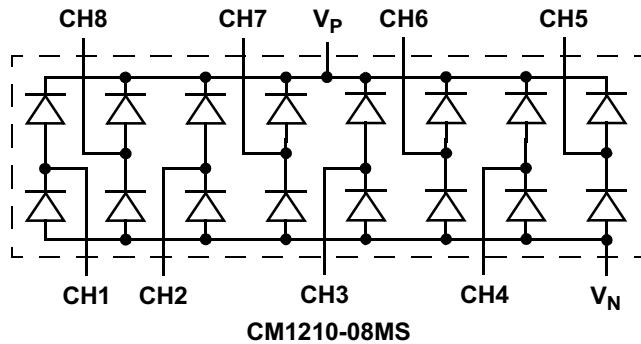
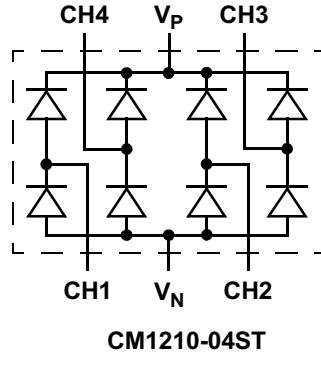
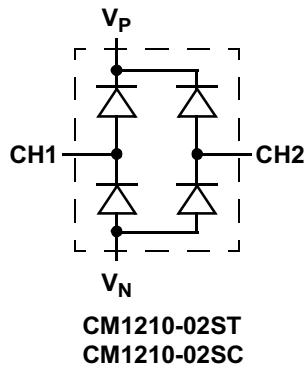
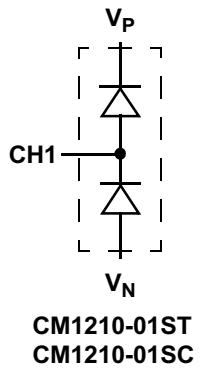
- USB2.0 ports at 480Mbps
- IEEE1394 Firewire ports at 400Mbps
- Gigabit Ethernet ports
- Flat panel display interfaces
- Wireless antennas
- General purpose high-speed data line ESD protection

### Product Description

The CM1210 family of diode arrays has been designed to provide ESD protection for electronic components or sub-systems requiring minimal capacitive loading. These devices are ideal for protecting systems with high data and clock rates or for circuits requiring low capacitive loading. Each ESD channel consists of a pair of diodes which will steer the ESD current pulse to either the positive ( $V_P$ ) or negative ( $V_N$ ) supply rail. The CM1210 will protect against ESD pulses up to  $\pm 6$  kV per the IEC 61000-4-2 standard.

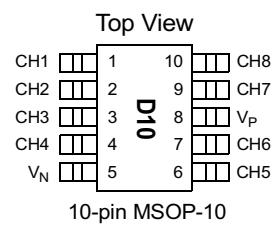
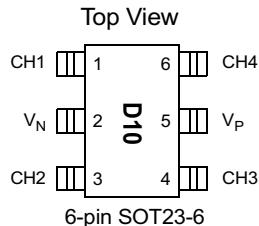
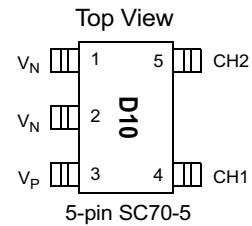
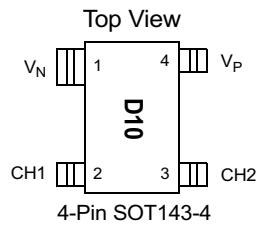
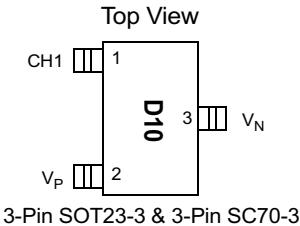
This device is particularly well-suited for systems using high-speed port implementations such as USB2.0, IEEE1394 (Firewire®, i.Link™), Gigabit Ethernet and corresponding ports in removable storage, digital camcorders, DVD-RW drives and other applications where extremely low loading capacitance with ESD protection are required in a small package footprint.

### Electrical Schematics





## PACKAGE / PINOUT DIAGRAMS



Note: This drawing is not to scale.

SOT23-3 & SC70-3 PACKAGE  
PIN DESCRIPTIONS

PIN	NAME	TYPE	DESCRIPTION
1	CH1	I/O	ESD Channel
2	V <sub>P</sub>	PWR	Positive voltage supply rail
3	V <sub>N</sub>	GND	Negative voltage supply rail

## SC70-5 PACKAGE PIN DESCRIPTIONS

PIN	NAME	TYPE	DESCRIPTION
1	V <sub>N</sub>	GND	Negative voltage supply rail
2	V <sub>N</sub>	GND	Negative voltage supply rail
3	V <sub>P</sub>	PWR	Positive voltage supply rail
4	CH1	I/O	ESD Channel
5	CH2	I/O	ESD Channel

## SOT23-6 PACKAGE PIN DESCRIPTIONS

PIN	NAME	TYPE	DESCRIPTION
1	CH1	I/O	ESD Channel
2	V <sub>N</sub>	GND	Negative voltage supply rail
3	CH2	I/O	ESD Channel
4	CH3	I/O	ESD Channel
5	V <sub>P</sub>	PWR	Positive voltage supply rail
6	CH4	I/O	ESD Channel

## SOT143-4 PACKAGE PIN DESCRIPTIONS

PIN	NAME	TYPE	DESCRIPTION
1	V <sub>N</sub>	GND	Negative voltage supply rail
2	CH1	I/O	ESD Channel
3	CH2	I/O	ESD Channel
4	CH3	I/O	ESD Channel
5	V <sub>P</sub>	PWR	Positive voltage supply rail
6	CH4	I/O	ESD Channel
7	CH5	I/O	ESD Channel
8	CH6	I/O	ESD Channel
9	CH7	I/O	ESD Channel
10	CH8	I/O	ESD Channel

## MSOP-10 PACKAGE PIN DESCRIPTIONS

PIN	NAME	TYPE	DESCRIPTION
1	CH1	I/O	ESD Channel
2	CH2	I/O	ESD Channel
3	CH3	I/O	ESD Channel
4	CH4	I/O	ESD Channel
5	V <sub>N</sub>	GND	Negative voltage supply rail
6	CH5	I/O	ESD Channel
7	CH6	I/O	ESD Channel
8	V <sub>P</sub>	PWR	Positive voltage supply rail
9	CH7	I/O	ESD Channel
10	CH8	I/O	ESD Channel



## Ordering Information

PART NUMBERING INFORMATION			
Pins	Package	Ordering Part Number <sup>1</sup>	Part Marking
3	SOT23-3	CM1210-01ST	D10
3	SC70-3	CM1210-01SC	D10
4	SOT143	CM1210-02ST	D10
5	SC70-5	CM1210-02SC	D10
6	SOT23-6	CM1210-04ST	D10
10	MSOP10	CM1210-08MS	D10

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

## Specifications

ABSOLUTE MAXIMUM RATINGS		
PARAMETER	RATING	UNITS
Supply Voltage ( $V_P - V_N$ )	8.0	V
Diode Forward DC Current (Note 1)	8	mA
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-65 to +150	°C
DC Voltage at any channel input	( $V_N - 0.5$ ) to ( $V_P + 0.5$ )	V
Package Power Rating SOT23-3 Package (CM1210-01ST) SC70-3 Package (CM1210-01SC) SOT143 Package (CM1210-02ST) SC70-5 Package (CM1210-02SC) SOT23-6 Package (CM1210-04ST) MSOP10 Package (CM1210-08MS)	225 200 225 200 225 400	mW mW mW mW mW mW

Note 1: Only one diode conducting at a time.

STANDARD OPERATING CONDITIONS		
PARAMETER	RATING	UNITS
Operating Temperature Range	-40 to +85	°C
Operating Supply Voltage ( $V_P - V_N$ )	0 to 5.5	V

ELECTRICAL OPERATING CHARACTERISTICS<sup>1</sup>

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT S
I <sub>P</sub>	Supply Current	(V <sub>P</sub> -V <sub>N</sub> )=3.3V			8.0	µA
V <sub>F</sub>	Diode Forward Voltage Top Diode Bottom Diode	I <sub>F</sub> = 8mA	0.60 0.60	0.80 0.80	0.95 0.95	V V
I <sub>LEAK</sub>	Channel Leakage Current			±0.1	±1.0	µA
C <sub>IN</sub>	Channel Input Capacitance	At 1 MHz, V <sub>P</sub> =3.3V, V <sub>N</sub> =0V, V <sub>IN</sub> =1.65V; Note 2 applies		1.0	1.3	pF
V <sub>ESD</sub>	ESD Protection Peak Discharge Voltage at any channel input, in system a) Contact discharge per IEC 61000-4-2 standard	Notes 2,3 and 5; T <sub>A</sub> =25°C	±6			kV
V <sub>CL</sub>	Channel Clamp Voltage CM1210-01ST, CM1210-01SC, CM1210-02ST, CM1210-02SC Positive Transients Negative Transients	At 8kV ESD HBM; Notes 2 & 4			V <sub>P</sub> + 10.0 V <sub>N</sub> - 10.0	V V
	Channel Clamp Voltage CM1210-04ST, CM1210-08MS Positive Transients Negative Transients	At 8kV ESD HBM; Notes 2 & 4			V <sub>P</sub> + 13.0 V <sub>N</sub> - 13.0	V V

Note 1: All parameters specified at T<sub>A</sub> = -40°C to +85°C unless otherwise noted.

Note 2: These parameters guaranteed by design and characterization.

Note 3: From I/O pins to V<sub>P</sub> or V<sub>N</sub> only. V<sub>P</sub> bypassed to V<sub>N</sub> with a 0.22µF ceramic capacitor (see Application Information for more details).

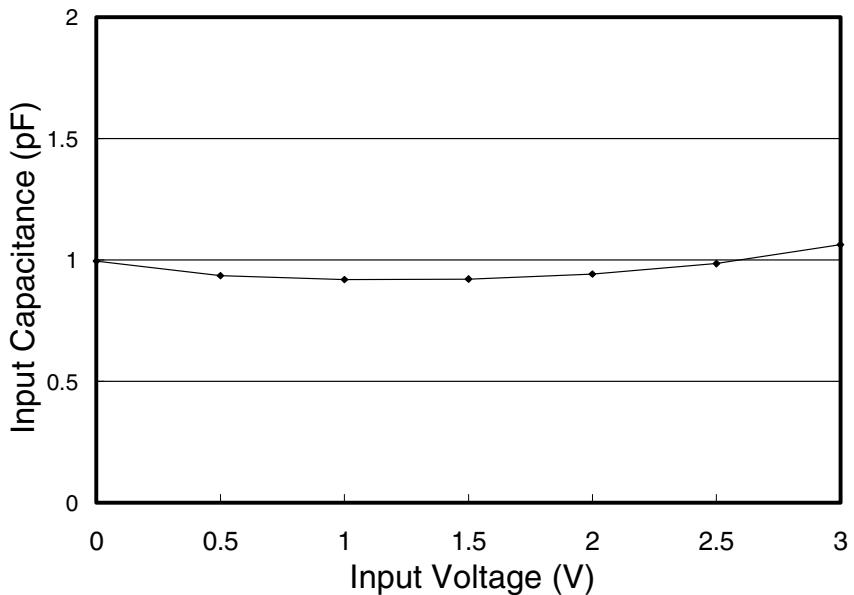
Note 4: Human Body Model per MIL-STD-883, Method 3015, C<sub>Discharge</sub> = 100pF, R<sub>Discharge</sub> = 1.5KΩ, V<sub>P</sub> = 3.3V, V<sub>N</sub> grounded.

Note 5: Standard IEC 61000-4-2 with C<sub>Discharge</sub> = 150pF, R<sub>Discharge</sub> = 330Ω, V<sub>P</sub> = 3.3V, V<sub>N</sub> grounded.



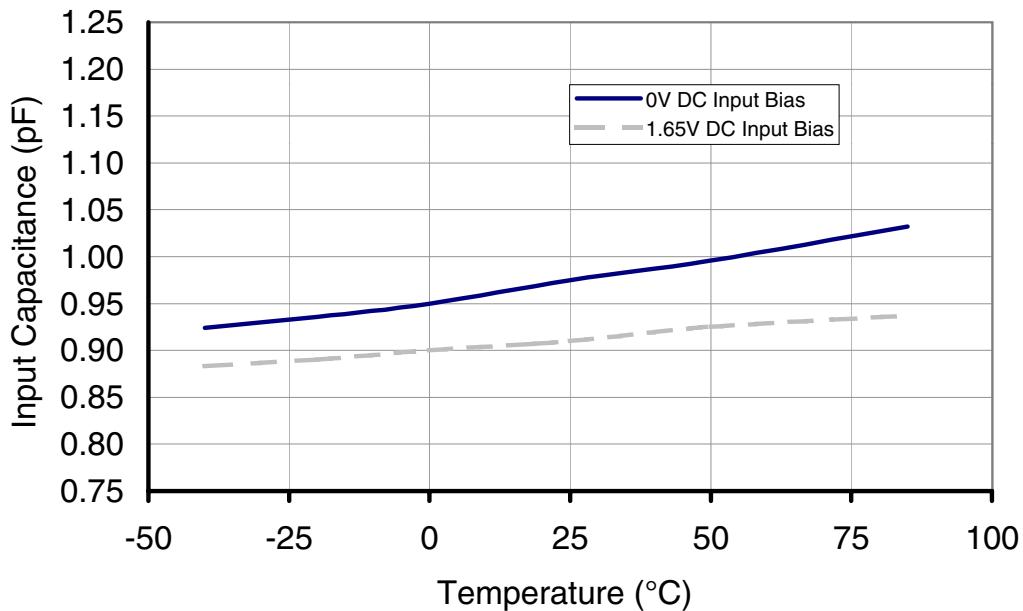
## Performance Information

### Input Channel Capacitance Performance Curves



**Typical Variation of  $C_{IN}$  vs.  $V_{IN}$**

( $f=1\text{MHz}$ ,  $V_P = 3.3\text{V}$ ,  $V_N = 0\text{V}$ ,  $0.1 \mu\text{F}$  chip capacitor between  $V_P$  and  $V_N$ ,  $25^\circ\text{C}$ )



**Typical Variation of  $C_{IN}$  vs. Temp**

( $f=1\text{MHz}$ ,  $V_{IN}=30\text{mV}$ ,  $V_P = 3.3\text{V}$ ,  $V_N = 0\text{V}$ ,  
 $0.1 \mu\text{F}$  chip capacitor between  $V_P$  and  $V_N$ )



## Performance Information (Cont'd)

Typical Filter Performance (nominal conditions unless specified otherwise, 50 Ohm Environment)

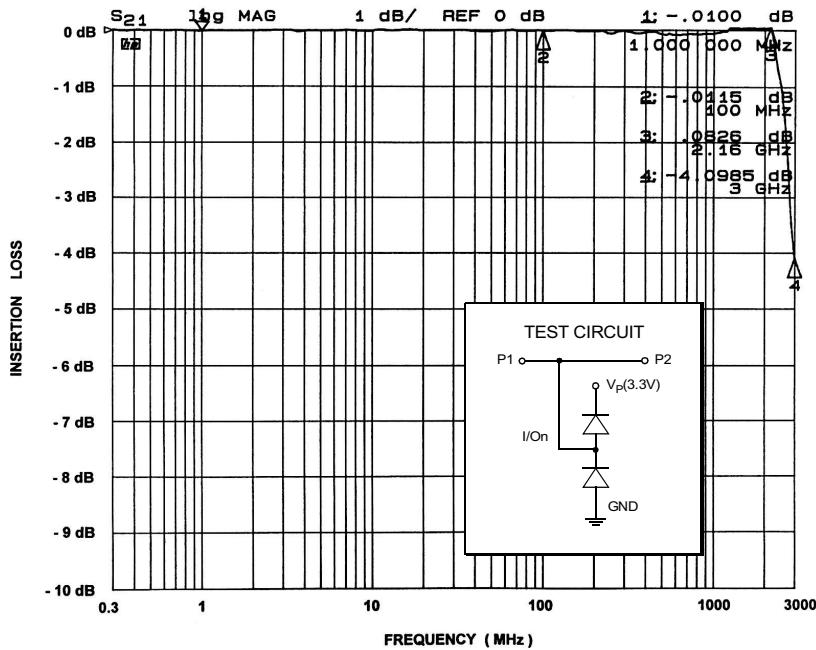


Figure 1. Insertion Loss (S<sub>21</sub>) VS. Frequency (0V DC Bias, V<sub>p</sub>=3.3V)

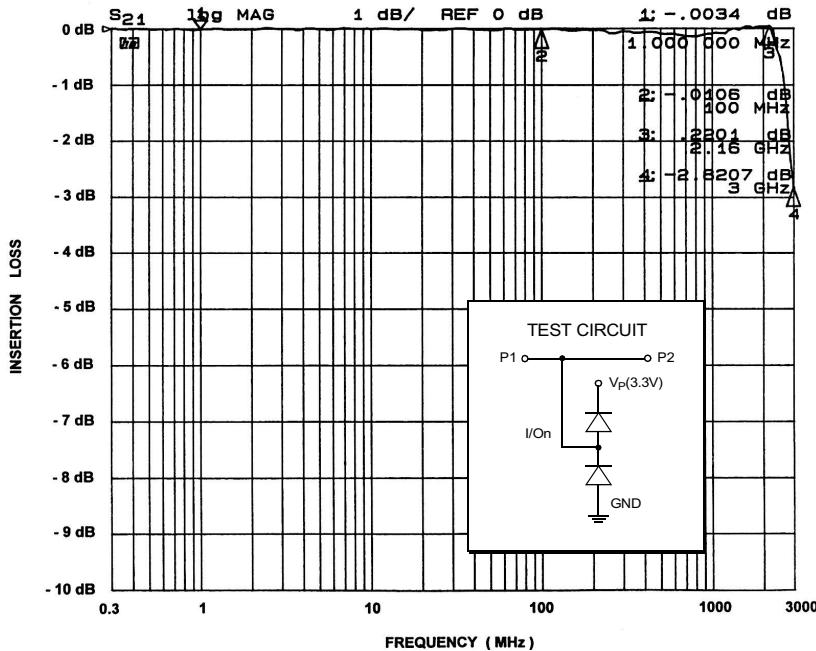


Figure 2. Insertion Loss (S<sub>21</sub>) VS. Frequency (2.5V DC Bias, V<sub>p</sub>=3.3V)



## Application Information

### Design Considerations

In order to realize the maximum protection against ESD pulses, care must be taken in the PCB layout to minimize parasitic series inductances on the Supply/Ground rails as well as the signal trace segment between the signal input (typically a connector) and the ESD protection device. Refer to [Figure 3](#), which illustrates an example of a positive ESD pulse striking an input channel. The parasitic series inductance back to the power supply is represented by  $L_1$  and  $L_2$ . The voltage  $V_{CL}$  on the line being protected is:

$$V_{CL} = \text{Fwd voltage drop of } D_1 + V_{SUPPLY} + L_1 \times d(I_{ESD}) / dt + L_2 \times d(I_{ESD}) / dt$$

where  $I_{ESD}$  is the ESD current pulse, and  $V_{SUPPLY}$  is the positive supply voltage.

An ESD current pulse can rise from zero to its peak value in a very short time. As an example, a level 4 contact discharge per the IEC61000-4-2 standard results in a current pulse that rises from zero to 30 Amps in 1ns. Here  $d(I_{ESD})/dt$  can be approximated by  $\Delta I_{ESD}/\Delta t$ , or  $30/(1 \times 10^{-9})$ . So just 910nH of series inductance ( $L_1$  and  $L_2$  combined) will lead to a 300V increment in  $V_{CL}$ !

Similarly for negative ESD pulses, parasitic series inductance from the  $V_N$  pin to the ground rail will lead to drastically increased negative voltage on the line being protected.

Another consideration is the output impedance of the power supply for fast transient currents. In the  $V_{CL}$  equation above, the  $V_{SUPPLY}$  term, in reality, is given by  $(V_{DC} + I_{ESD} \times R_{OUT})$ , where  $V_{DC}$  and  $R_{OUT}$  are the nominal supply DC output voltage and effective output impedance of the power supply respectively. As an example,

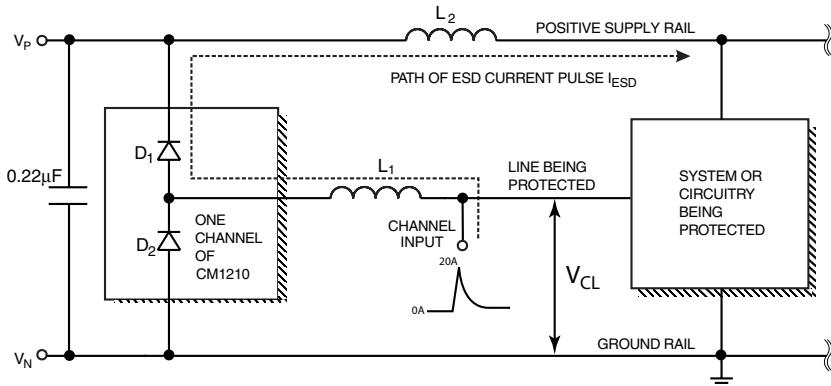
a  $R_{OUT}$  of 1 ohm would result in a 10V increment in  $V_{CL}$  for a peak  $I_{ESD}$  of 10A.

If the inductances and resistance described above are close to zero, the rail-clamp ESD protection diodes will do a good job of protection. However, since this is not possible in practical situations, a bypass capacitor must be used to absorb the very high frequency ESD energy. So for any brand of rail-clamp ESD protection diodes, a bypass capacitor should be connected between the  $V_P$  pin of the diodes and the ground plane ( $V_N$  pin of the diodes) as shown in the Application Circuit diagram below. A value of  $0.22\mu F$  is adequate. Ceramic chip capacitors mounted with short printed circuit board traces are good choices for this application. Electrolytic capacitors should be avoided as they have poor high frequency characteristics. For extra protection, connect a zener diode in parallel with the bypass capacitor to mitigate the effects of the parasitic series inductance inherent in the capacitor. The breakdown voltage of the zener diode should be slightly higher than the maximum supply voltage.

As a general rule, the ESD Protection Array should be located as close as possible to the point of entry of expected electrostatic discharges. The power supply bypass capacitor mentioned above should be as close to the  $V_P$  pin of the Protection Array as possible, with minimum PCB trace lengths to the power supply, ground planes and between the signal input and the ESD device to minimize stray series inductance.

### Additional Information

See also California Micro Devices Application Notes AP209, "Design Considerations for ESD Protection" and APxxx, "ESD Protection for USB 2.0 Systems".



**Figure 3. Application of Positive ESD Pulse between Input Channel and Ground**



## Mechanical Details

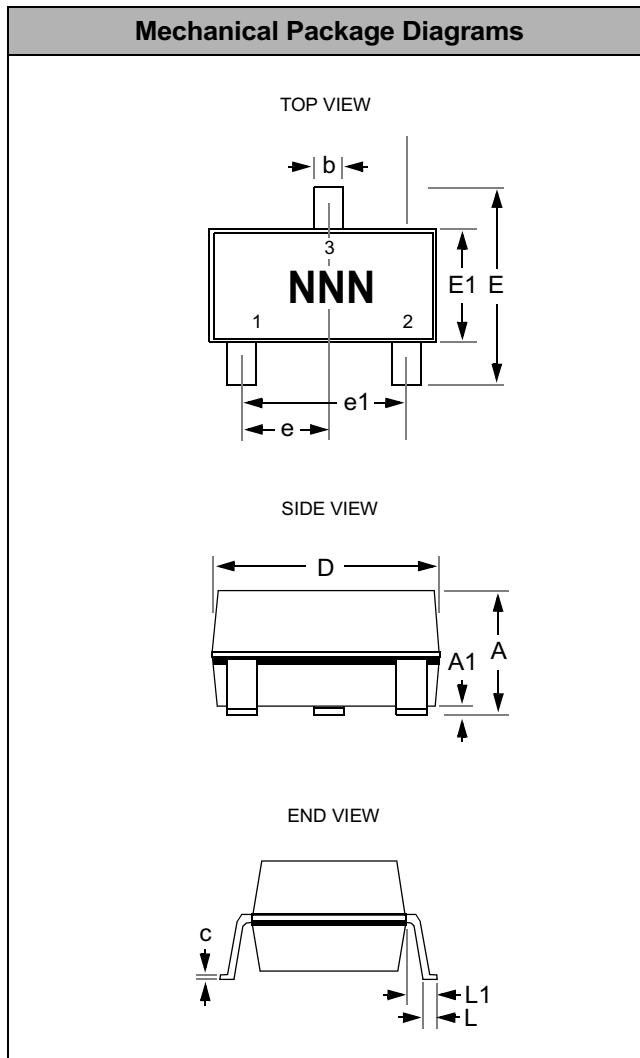
The CM1210 is available in SOT23-3, SC70-3, SC70-5, SOT23-6, SOT143-4 and MSOP-10 packages. The various package drawings are presented below.

### SOT23-3 Mechanical Specifications

Dimensions for CM1210 devices packaged in 3-pin SOT23 packages are presented below.

For complete information on the SOT23-3 package, see the California Micro Devices SOT23 Package Information document.

PACKAGE DIMENSIONS						
Package	SOT23-3 (JEDEC name is TO-236)					
Pins	3					
Dimensions	Millimeters		Inches			
	Min	Max	Min	Max		
A	0.89	1.12	0.0350	0.0441		
A1	0.01	0.10	0.0004	0.0039		
b	0.30	0.50	0.0118	0.0197		
c	0.08	0.20	0.0031	0.0079		
D	2.80	3.04	0.1102	0.1197		
E	2.10	2.64	0.0827	0.1039		
E1	1.20	1.40	0.0472	0.0551		
e	0.95 BSC		0.0374 BSC			
e1	1.90 BSC		0.0748 BSC			
L	0.40	0.60	0.0157	0.0236		
L1	0.54 REF		0.0213 REF			
# per tape and reel	3000 pieces					
Controlling dimension: millimeters						



Package Dimensions for SOT23-3.



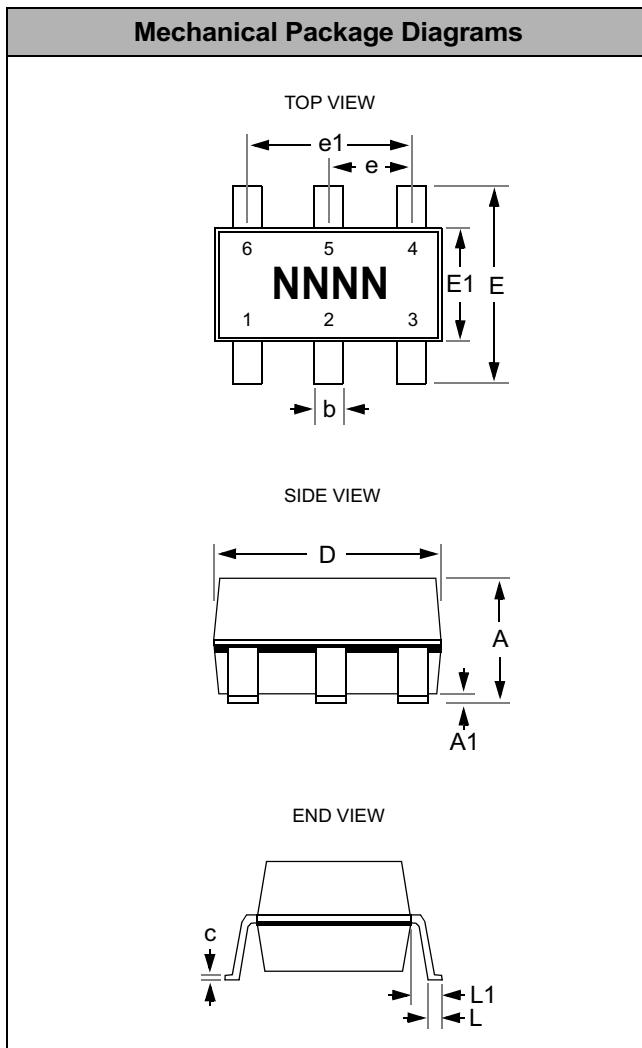
## Mechanical Details (cont'd)

### SOT23-6 Mechanical Specifications

CM1210 devices are packaged in 6-pin SOT23 packages. Dimensions are presented below.

For complete information on the SOT23-6 package, see the California Micro Devices SOT23 Package Information document.

PACKAGE DIMENSIONS						
Package	SOT23-6 (JEDEC name is MO-178)					
Pins	6					
Dimensions	Millimeters		Inches			
	Min	Max	Min	Max		
A	--	1.45	--	0.0571		
A1	0.00	0.15	0.0000	0.0059		
b	0.30	0.50	0.0118	0.0197		
c	0.08	0.22	0.0031	0.0087		
D	2.75	3.05	0.1083	0.1201		
E	2.60	3.00	0.1024	0.1181		
E1	1.45	1.75	0.0571	0.0689		
e	0.95 BSC		0.0374 BSC			
e1	1.90 BSC		0.0748 BSC			
L	0.30	0.60	0.0118	0.0236		
L1	0.60 REF		0.0236 REF			
# per tape and reel	3000 pieces					
Controlling dimension: millimeters						



Package Dimensions for SOT23-6.



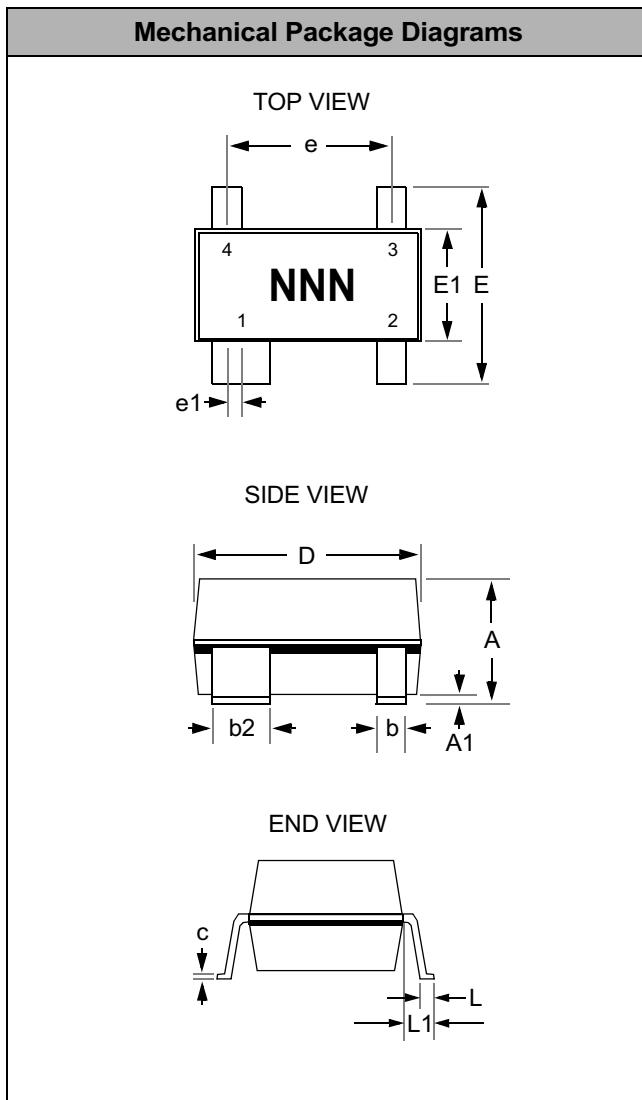
## Mechanical Details (cont'd)

### SOT143 Mechanical Specifications

Dimensions for CM1210 devices packaged in 4-pin SOT143 packages are presented below.

For complete information on the SOT143 package, see the California Micro Devices SOT143 Package Information document.

PACKAGE DIMENSIONS						
Package	SOT143					
Pins	4					
Dimensions	Millimeters		Inches			
	Min	Max	Min	Max		
A	0.80	1.22	0.031	0.048		
A1	0.05	0.15	0.002	0.006		
b	0.30	0.50	0.012	0.019		
b2	0.76	0.89	0.030	0.035		
c	0.08	0.20	0.003	0.008		
D	2.80	3.04	0.110	0.119		
E	2.10	2.64	0.082	0.103		
E1	1.20	1.40	0.047	0.055		
e	1.92 BSC		0.075 BSC			
e1	0.20 BSC		0.008 BSC			
L	0.4	0.6	0.016	0.024		
L1	0.54 REF		0.021 REF			
# per tape and reel	3000 pieces					
Controlling dimension: millimeters						



Package Dimensions for SOT143.



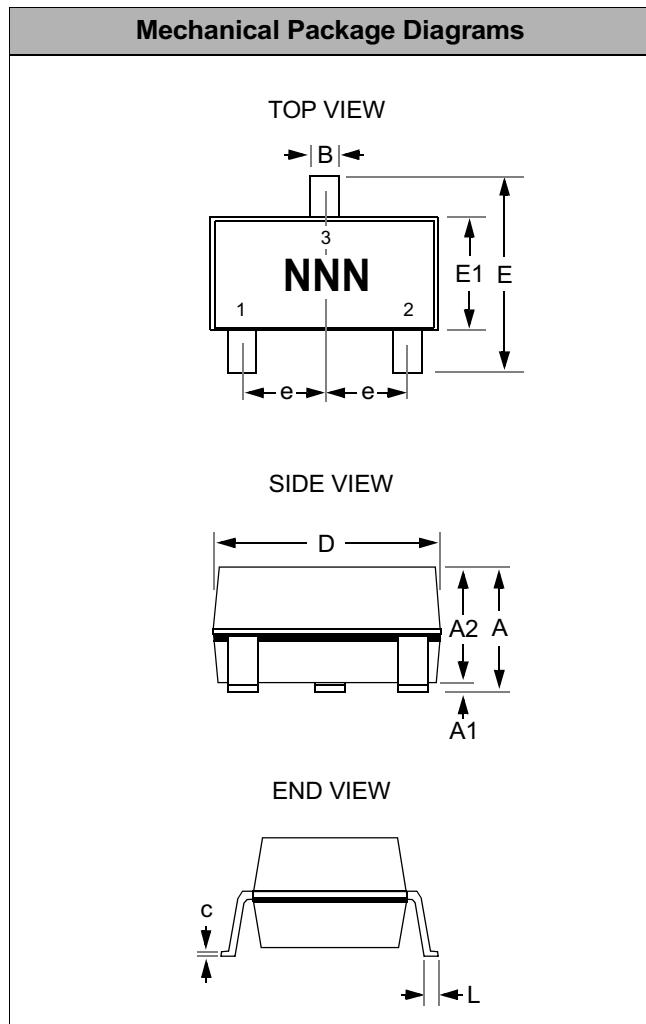
## Mechanical Details (cont'd)

### SC70-3 Mechanical Specifications

Dimensions for CM1210 devices packaged in 3-pin SC70 packages are presented below.

For complete information on the SC70-3 package, see the California Micro Devices SC70 Package Information document.

PACKAGE DIMENSIONS		
Package	SC70-3 (JEDEC name is MO-203 Issue A)	
Pins	3	
Dimensions	Millimeters	
	Min	Max
A	0.80	1.10
A1	0.00	0.10
A2	0.70	1.00
B	0.15	0.30
c	0.08	0.25
D	1.85	2.25
E1	1.15	1.35
e	0.65 BSC	
E	2.00	2.40
L	0.26	0.46
# / tape and reel	3000 pieces	



Package Dimensions for SC70-3.



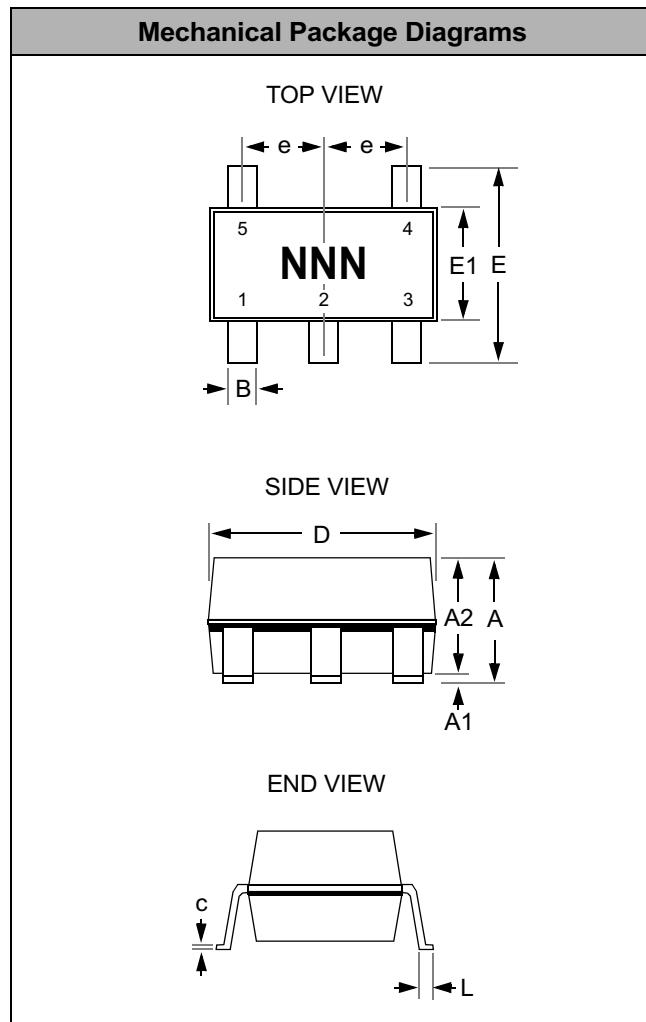
## Mechanical Details (cont'd)

### SC70-5 Mechanical Specifications:

Dimensions for CM1210 devices packaged in 5-pin SC70 packages are presented below.

For complete information on the SC70-5 package, see the California Micro Devices SC70 Package Information document.

PACKAGE DIMENSIONS		
Package	SC70-5 (JEDEC name is MO-203 Issue A)	
Pins	5	
Dimensions	Millimeters	
	Min	Max
A	0.80	1.10
A1	0.00	0.10
A2	0.70	1.00
B	0.15	0.30
c	0.08	0.25
D	1.85	2.25
E1	1.15	1.35
e	0.65 BSC	
E	2.00	2.40
L	0.26	0.46
# / tape and reel	3000 pieces	



Package Dimensions for SC70-5.



## Mechanical Details (cont'd)

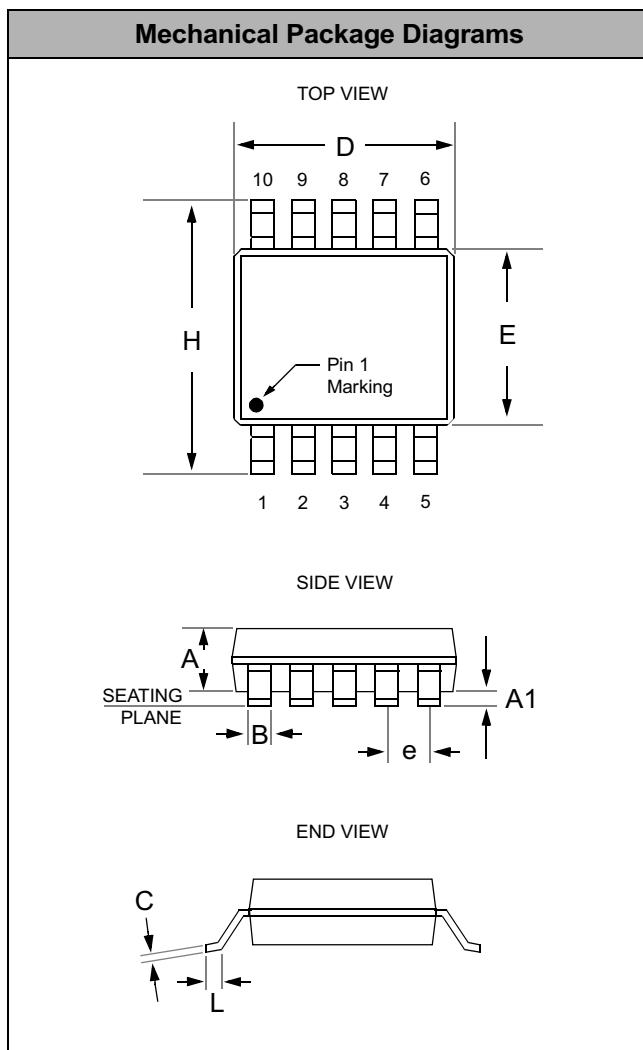
### MSOP Mechanical Specifications

CM1210 devices are packaged in 10-pin MSOP packages. Dimensions are presented below.

For complete information on the MSOP-10 package, see the California Micro Devices MSOP Package Information document.

PACKAGE DIMENSIONS				
Package	MSOP			
Pins	10			
Dimensions	Millimeters		Inches	
	Min	Max	Min	Max
A	0.75	0.95	0.028	0.038
A1	0.05	0.15	0.002	0.006
B	0.18	0.40	0.006	0.016
C	0.18		0.007	
D	2.90	3.10	0.114	0.122
E	2.90	3.10	0.114	0.122
e	0.50 BSC		0.0196 BSC	
H	4.76	5.00	0.187	0.197
L	0.40	0.70	0.0137	0.029
# per tube	80 pieces*			
# per tape and reel	4000			
Controlling dimension: inches				

\* This is an approximate number which may vary.



Package Dimensions for MSOP-10